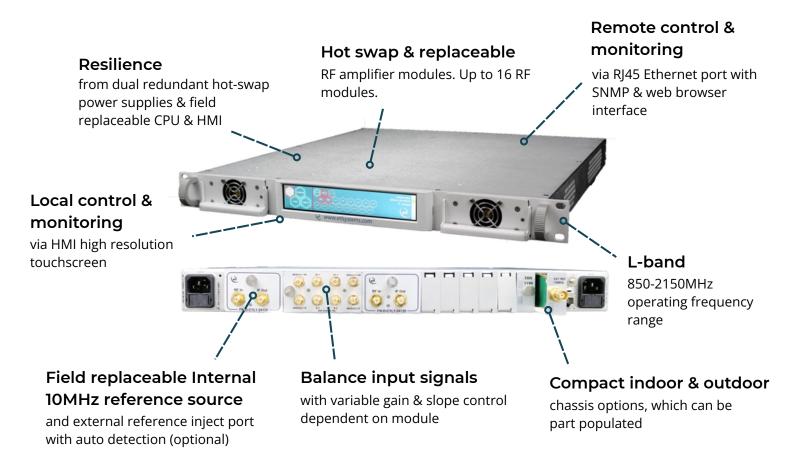


Alto L-band Redundant Amplifier Module

with low noise, high linearity, variable gain and slope control

The L-band redundant low noise amplifier module is designed to work in the Genus 1U redundant chassis range, operating over 850-2150 MHz. The module has low noise, high linearity, with variable gain and slope control.



Chassis Specification				
Dimensions/Weight/Colour	1U high x 550mm deep x 19" wide / <10kg / RAL9003 - white (semi-matte)			
Capacity	17 module slots. Note: Actual modules may require >1 slot. Refer to required module spec table.			
Temperature	Operating: 0°C to +45°C Storage: -20°C to +75°C			
Location/Humidity/Altitude	ion/Humidity/Altitude Indoor use only / 20 to 90% non-condensing / 2,000m AMSL (Operational) 8,000m AMSL (Storag Above Mean Sea Level			
Control & Monitoring	Local: HMI, capacitive touch screen Remote: Ethernet via RJ45, 10BaseT/100 BaseTx. ETL TCP/IP, SNMPv2/3, HTTPS & built-in web server. HMI and CPU field replaceable.			
MTTR	20 minutes (15 minutes to retrieve spare part and 5 mins to replace). Applies to LRUs only and assumed in-house stock.			
AC Input/Consumption	85-264Vac 50/60Hz / 275W max. consumption at steady state			
PSU Redundancy	Dual redundant and alarmed. Diode OR. Hot swappable.			
Input & Output Ports	Dependent upon module fitted			

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Smart Amplifier Module

Compact form factor allows multiple modules to be housed in the 1U GENUS chassis. Each module occupies 1 slot in the chassis.

High linearity ensures overall RF gain signal performance is optimised.

Low noise for prime signal quality.

		1:1 Redundant Amplifier Module - RF F	Parameters	
Model Numb	pers	ALT-G1R-L1-105 (The spec below is for ALT-G1R-L1-105 in 1:1 redundancy configuration with SWF-G1R-SX-101)		
Frequency Range		850 - 2150 MHz		
Size		1 slot wide		
RF Ports		50Ω SMA		
MTBF		>150,000 hrs. MTBF of each amp module. These are hot-swap		
Gain		28 ± 2.0 dB max. -2 ± 2.0 dB min.		
Gain	850 - 2150MHz	±0.75	When set to 0dB slope. In manual gain control	
Flatness	Any 36MHz	±0.25	mode, not AGC.	
Gain Steps		0.25 ± 0.15 in i	0.25 ± 0.15 in manual gain mode	
Slope Control Range		0 to 6 dB	Pivot point is at 2150MHz. This is the point of max gain when positive slope is set to a value other than 0dB.	
Slope Control Steps		1 ± 0.25		
Input Return	Loss	16 dB typ.	. 12 dB min.	
Output Return Loss		16 dB typ. 12 dB min.		
Isolation		60dB Typ. 50dB Min.	With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB to dB for different gain levels.	
Reverse Gain		< -60	< -60 dB typ.	
	Тур.	8 dB	At max. gain	
Noise Figure	Max.	10 dB	At max. gain	
4 10 660	Тур.	21 dBm	At max. gain	
1dB GCP	Max.	18 dBm	At max. gain	
0.100	Тур.	31 dBm	At max. gain	
OIP3	Max.	28 dBm	At max. gain	
0.100	Тур.	42 dBm		
OIP2	Max.	38 dBm		
In band, signal independent spurii		<-85 dBm max.	Very low level spurii from CPU clock, switch mode PSU and other control electronics inside the chassis.	
Maximum In	put Level	+20 dBm	For no damage. Non-operational.	





Smart Amplifier Module

Compact form factor allows multiple modules to be housed in the 1U GENUS chassis. Each module occupies 1 slot in the chassis.

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Low noise for prime signal quality.

		1:1 Redundant Amplifier Module - RF F	Parameters	
Model Numb	pers	ALT-G1R-L1-105 (The spec below is for ALT-G1R-L1-105 in 1:1 redundancy configuration with SWF-G1R-SX-114)		
Frequency Range		850 - 2150 MHz		
Size		1 slot wide		
RF Ports		50Ω SMA		
MTBF		>150,000 hrs. MTBF of each amp module. These are hot-swap		
Gain		25 ± 2.0 dB max. -5 ± 2.0 dB min.		
Gain	850 - 2150MHz	±0.8	When set to 0dB slope. In manual gain control	
Flatness	Any 36MHz	±0.25	mode, not AGC.	
Gain Steps		0.25 ± 0.15 in i	0.25 ± 0.15 in manual gain mode	
Slope Control Range		0 to 5 dB	Pivot point is at 2150MHz. This is the point of max gain when positive slope is set to a value other than 0dB.	
Slope Control Steps		1 :	1 ± 0.25	
Input Return	Loss	14 dB typ.	. 10 dB min.	
Output Return Loss		14 dB typ. 10 dB min.		
Isolation		60dB Typ. 50dB Min.	With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB to dB for different gain levels.	
Reverse Gain		< -60 dB typ.		
	Тур.	10 dB	At max. gain	
Noise Figure	Max.	12 dB	At max. gain	
4 10 660	Тур.	19 dBm	At max. gain	
1dB GCP	Max.	16 dBm	At max. gain	
0.100	Тур.	29 dBm	At max. gain	
OIP3	Max.	26 dBm	At max. gain	
0.100	Тур.	47 dBm		
OIP2	Max.	44 dBm		
In band, signal independent spurii		<-85 dBm max.	Very low level spurii from CPU clock, switch mode PSU and other control electronics inside the chassis.	
Maximum In	put Level	+20 dBm	For no damage. Non-operational.	



Interface, Monitoring & Alarms					
Control Method	Local and remote as provided by selected chassis				
LNB Power	None				
Environmental					
On another Temperature	-0°C to +50°C	Up to 8 modules in a chassis.			
Operating Temperature	-0°C to +45°C	Up to 16 modules in a chassis.			
Storage Temperature	-20°C to +75°C				
Location	Indoor use only, within parent GENUS chassis				
Humidity	20 to 90% non-condensing, relative humidity				
Altitude	10,000ft / 3,000m above mean sea level				
Physical Dimensions & Parameters					
Weight	<0.35kg typ.				

The performance quoted above is for a standalone amplifier. For in-chassis performance, see relevant spec. tables.

Note 1: The specification is subject to regular reviews and will be updated from time to time as part of our continuing product development and improved spec accuracy.

Note 2: Operation beyond the quoted limits stated above may cause instantaneous and permanent damage.